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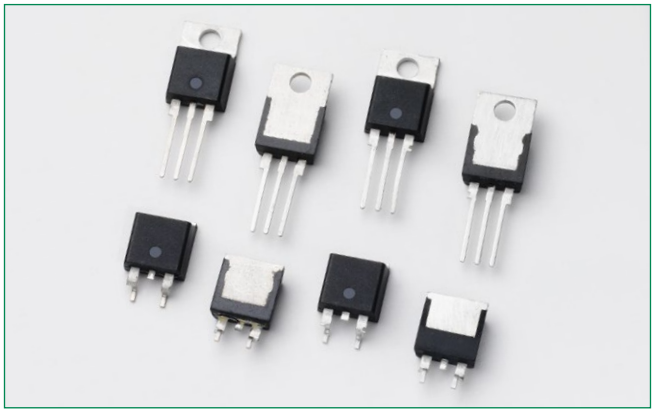
Thyristors

12 Amp Alternistor (High Communitation) Triac for LED dimmer Application

Q6012xH1LED Series

RoHS



Description

Q6012xH1LED series is designed to meet low load current characteristics typical in LED lighting applications.

By keeping holding current at 8mA maximum, this Triac series is characterized and specified to perform best with LED loads. The Q6012xH1LED series is best suited for LED dimming controls to obtain the lowest levels of light output with a minimum probability of flickering.

Agency Approval

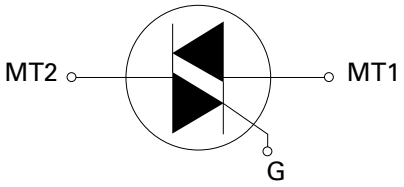
Agency	Agency File Number
	E71639*

* - L Package only

Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
V_{DRM}/V_{RRM}	600	V
I_{GT}	10	mA

Schematic Symbol



Features

- As low as 8mA max holding current
- L-Package is UL Recognized for 2500Vrms
- 110°C rated junction temperature
- di/dt performance of 70A/µs
- QUADRAC version includes intergrated DIAC
- Provides full control of light out put at the extreme low end of load conditions.
- 2500V_{AC} min isolation between mounting tab and active terminals
- Improves margin of safe operation with less heat sinking required
- Enable survivability of typically LED load operating characteristics
- Simplicity of circuit design & layout
- UL Recognized to UL 1557

Applications

Excellent for AC switching and phase control applications such as heating, lighting, and motor speed controls.

Typical applications are AC solid-state switches,lighting controls with LED lamp loads, small low current motor in power tools, lower current motor in home/brown goods appliances.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

Additional Information

Datasheet | Resources | Samples

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Absolute Maximum Ratings

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	Q6012LH1LED	T_C = 90°C	12	A
		Q6012RH1LED Q6012NH1LED			
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_J initial = 25°C)	f = 50 Hz	t = 20 ms	110	A
		f = 60 Hz	t = 16.7 ms	120	
I^2t	I^2t Value for fusing		t_p = 8.3 ms	60	A^2s
di/dt	Critical rate of rise of on-state current	f = 120 Hz	T_J = 110°C	70	A/µs
I_{GTM}	Peak gate trigger current	$t_p \leq 10$ µs; $I_{GT} \leq I_{GTM}$	T_J = 110°C	2.0	A
$P_{G(AV)}$	Average gate power dissipation		T_J = 110°C	0.5	W
T_{stg}	Storage temperature range			-40 to 150	°C
T_J	Operating junction temperature range			-40 to 110	°C

Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Test Conditions	Quadrant		Value	Unit
I_{GT}	V_D = 12V R_L = 60 Ω	I – II – III	MAX.	10	mA
V_{GT}		I – II – III	MAX.	1.3	V
V_{GD}	$V_D = V_{DRM}$ R_L = 3.3 kΩ T_J = 110°C	I – II – III	MIN.	0.2	V
I_H	I_T = 20mA		MAX.	8	mA
dv/dt	$V_D = V_{DRM}$ Gate Open T_J = 110°C		MIN.	45	V/µs
(dv/dt)c	(di/dt)c = 6.5 A/ms T_J = 110°C		MIN.	2	V/µs
t_{gt}	$I_G = 2 \times I_{GT}$ PW = 15µs I_T = 17.0 A(pk)		TYP.	4	µs

Static Characteristics

Symbol	Test Conditions			Value	Unit
V_{TM}	I_{TM} = 17.0A t_p = 380 µs		MAX.	1.60	V
I_{DRM} I_{RRM}	$V_D = V_{DRM} / V_{RRM}$	T_J = 25°C	MAX.	10	µA
		T_J = 110°C		1	mA

Thermal Resistances

Symbol	Parameter		Value	Unit
$R_{\theta(J-C)}$	Junction to case (AC)	Q6012LH1LED	2.3	°C/W
		Q6012RH1LED Q6012NH1LED	1.2	

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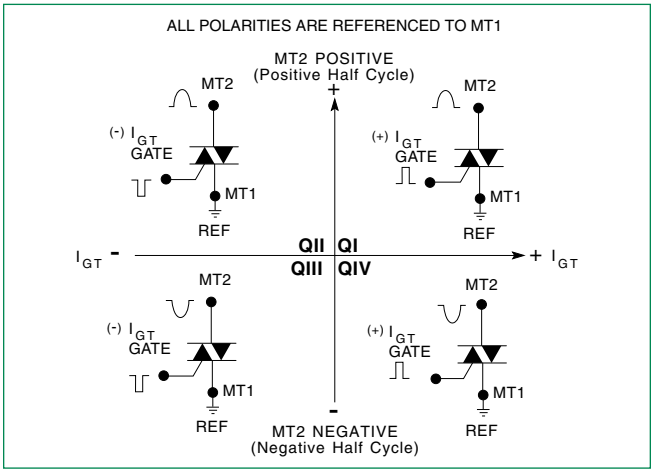
Figure 1: Definition of Quadrants



Note: Alternistors will not operate in QIV

Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature

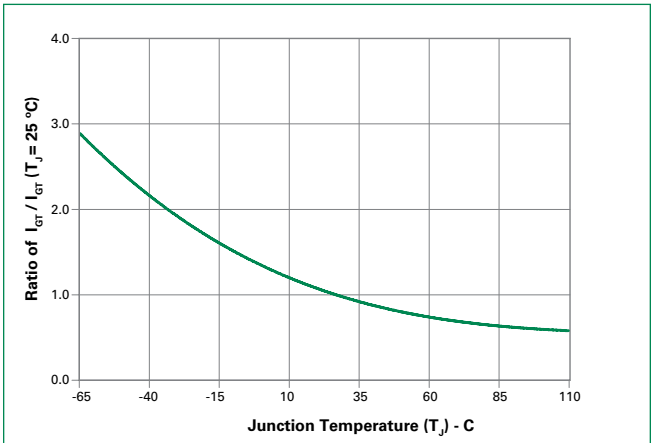


Figure 3: Normalized DC Holding Current vs. Junction Temperature

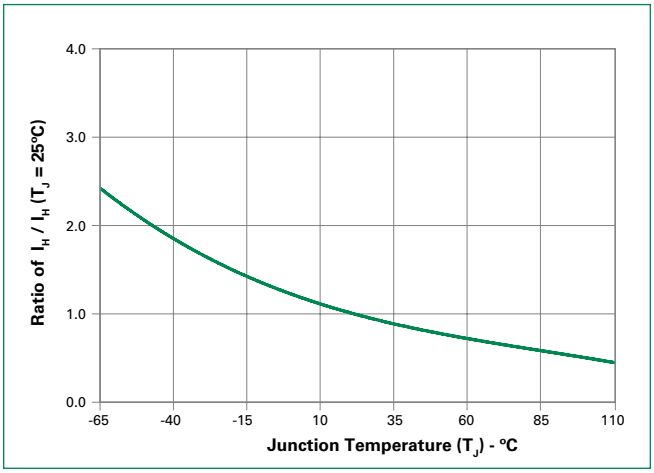


Figure 4: Normalized DC Gate Trigger Voltage for All Quadrants vs. Junction Temperature

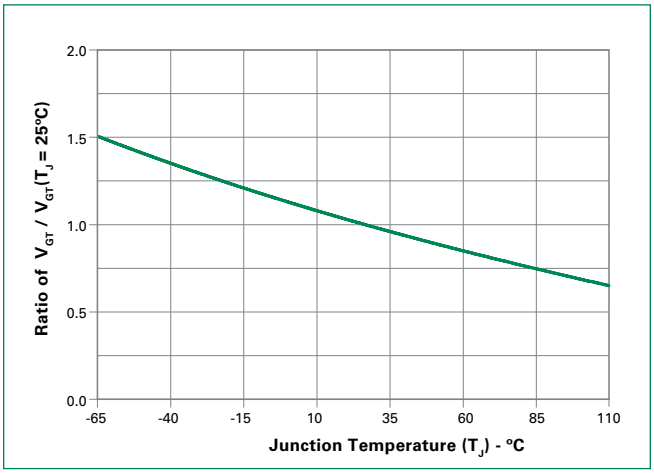


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

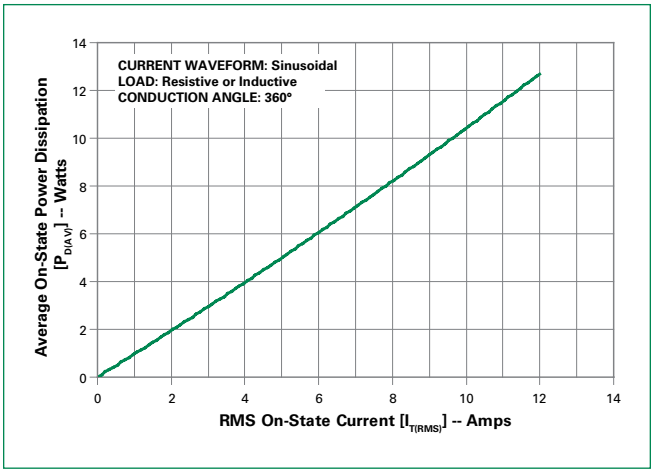


Figure 6: Maximum Allowable Case Temperature vs. On-State Current

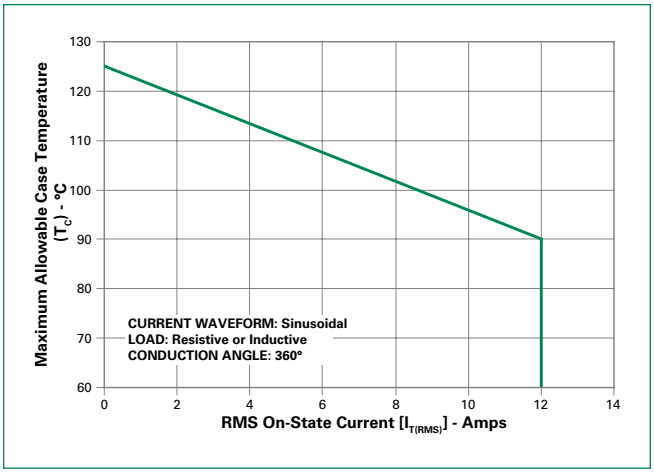


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Figure 7: On-State Current vs. On-State Voltage (Typical)

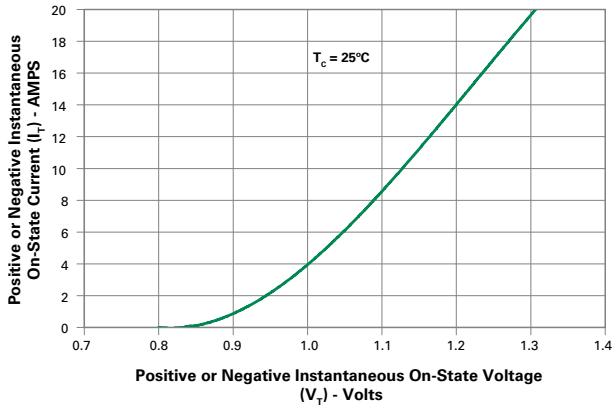
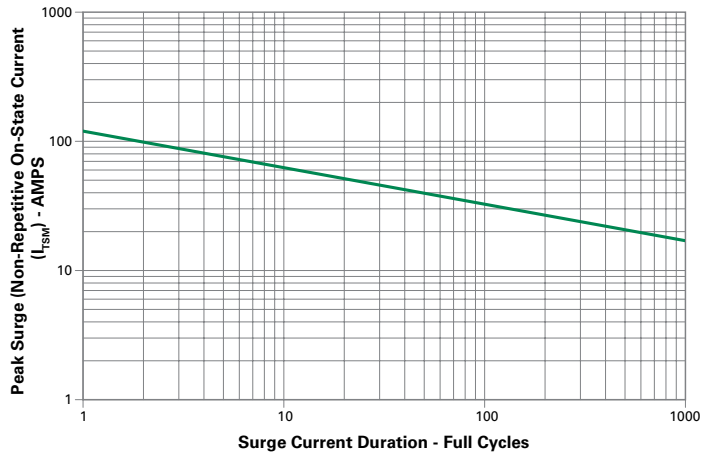


Figure 8: Surge Peak On-State Current vs. Number of Cycles

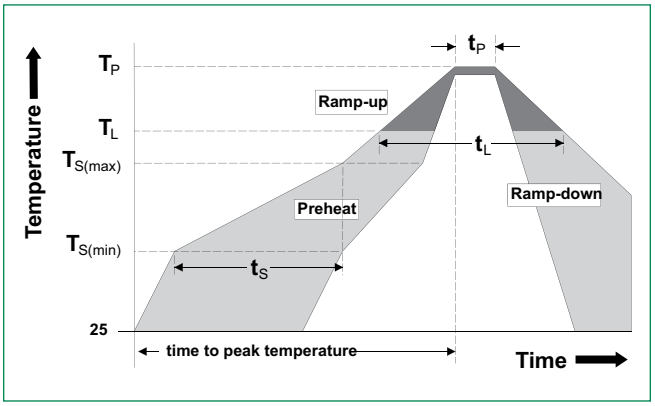


Supply Frequency: 60Hz Sinusoidal
Load: Resistive
RMS On-State Current [$I_{T(RMS)}$: Maximum]
Rated Value at Specific Case Temperature

Notes:
1. Gate control may be lost during and immediately following surge current interval.
2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	**- Temperature Min ($T_{s(min)}$)**	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	**- Temperature (T_L) (Liquidus)**	217°C
	- Time (min to max) (t_s)	60 – 150 seconds
Peak Temperature (T_p)		$260^{+0/-5}$ °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0
Terminal Material	Copper Alloy

Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell time
Temperature/Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

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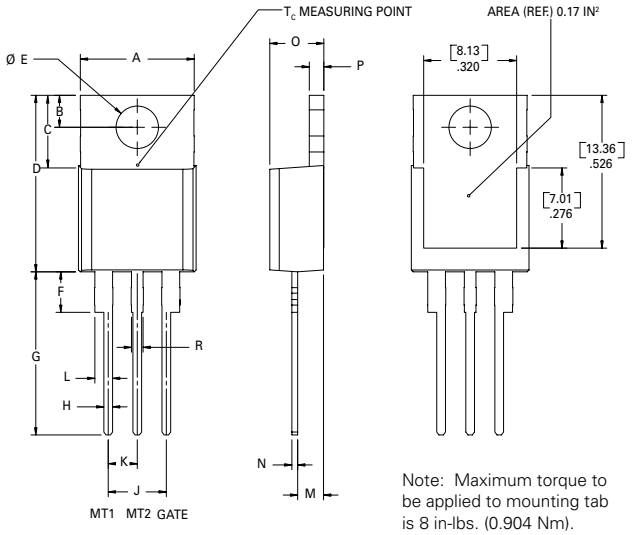
Dimensions — TO-220AB (L-Package) — Isolated Mounting Tab



Note: Maximum torque to be applied to mounting tab is 8 in-lbs. (0.904 Nm).

Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

Product Selector

Part Number	Gate Sensitivity Quadrants	Type	Package
	I – II – III		
Q6012LH1LED	10mA	Alternistor Triac	TO-220L
Q6012RH1LED			TO-220R
Q6012NH1LED			TO-263 D² - PAK

Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
Q6012LH1LEDTP	Q6012LH1	2.2 g	Tube Pack	500 (50 per tube)
Q6012RH1LEDTP	Q6012RH1	2.2 g	Tube Pack	500 (50 per tube)
Q6012NH1LEDTP	Q6012NH1	1.6 g	Tube Pack	500 (50 per tube)
Q6012NH1LEDRP	Q6012NH1	1.6 g	Embossed Carrier	500

Part Numbering System

Q 60 12 L H1 LED

DEVICE TYPE
Q: Alternistor Triac

VOLTAGE RATING
60: 600V

CURRENT RATING
12: 12A

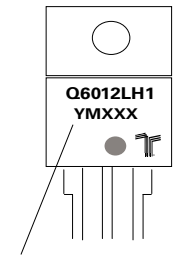
LED LIGHTING APPLICATION

SENSITIVITY & TYPE
H1: 10mA (QI, II & III)

PACKAGE TYPE
L : TO-220 Isolated
R : TO-220 Non-Isolated
N : TO-263 (D² - PAK)

Part Marking System

TO-220 AB - (L & R Package)
TO-263 AB - (N Package)



Date Code Marking
Y:Year Code
M: Month Code

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